## NSN 5961-01-245-6629

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## Inclosure Material:

Metal

**Overall Length:** 

0.210 inches

## Terminal Length:

0.750 inches

## **Overall Diameter:**

0.230 inches

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-46

## **Mounting Method:**

Terminal

## Terminal Circle Diameter:

0.100 inches

#### Features Provided:

Hermetically sealed case and quality assurance level tx

#### Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

25.0 collector to base voltage/static/emitter open and 18.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open

#### **Current Rating Per Characteristic:**

200.00 milliamperes source cutoff current

#### **Power Rating Per Characteristic:**

0.3 watts small-signal input power, common-collector preset

#### Transfer Ratio:

40.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

## **Special Features:**

Junction pattern arrangement: pnp

#### Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

## Terminal Type And Quantity:

3 uninsulated wire lead

## **Specification Data:**

81349-mil-s-19500/283 government specification

#### Shelf Life:

N/a

## Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0

